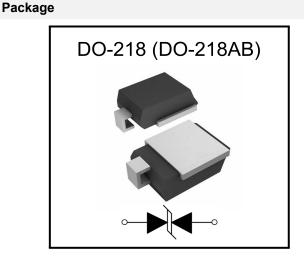


Transient Voltage Suppressor

Features

- · Excellent clamping capability
- · Low leakage current
- · Low capacitance
- · High surge capability
- · Glass passivated chip
- · Epoxy resin package
- · Will not fatigue
- · RoHS Compliant
- · AEC-Q101 qualified
- Meets ISO7637-2、16750-2 surge specifiation
- ISO 7637-2 P5a:
 - 12V System (65-87V 0.5-4Ω 40-400ms)
 - 24V System (123-174V 1-8Ω 100-350ms)



Mechanical Characteristics

- Package: DO-218 plastic package
- · Lead Finish: Matte Tin
- · Case Material: Epoxy Molding Compound
- · UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020

Applications

- · Auto powers system
- Can-bus
- ABS powers
- · Automotive instrument
- Car GPS

Making Code



Summary of Packing Options

Package		Packing Description	Packing Quantity	Industry Standard	
	DO-218	Tape/Reel,13" reel	750	EIA-481-1	

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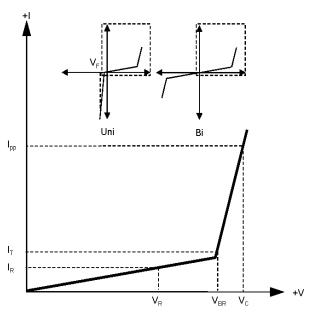




Transient Voltage Suppressor

Electrical Parameters

Parameter	Definition		
C.	Junction Capacitance - typical capacitance		
OJ	measured with 0V or V _R bias		
	Peak Pulse Current - maximum rated peak		
Ірр	impulse current		
	Clamping Voltage - Peak voltage measured		
V _C	across the suppressor at a specified lppm		
V	Breakdown Voltage - Maximum voltage that flows		
V_{BR}	though the TVS at a specified test current (I_T)		
1_	Leakage Current - maximum peak off-state		
I _R	current measured at V _R		
	Peak Off-state Voltage - maximum voltage		
V_{R}	that can be applied while maintaining off state		



Absolute Maximum Ratings (T_A=+25°C, unless otherwise noted)

Parameter	Symbol	Value	Units
Peak Pulse Power Dissipation (Note1)	P _{PPM}	6600	W
Peak Pulse Power Dissipation (Note2)	P _{PPM1}	5200	W
Steady State Power Dissipation (Note3)	P _D	8	W
Peak Forward Surge Current (Note4)	I _{FSM}	700	А
Maximum Instantaneous Forward Voltage at 100A	V _{FM}	3.5	V
Typical Thermal Resistance Junction to Lead	$R_{ heta JL}$	0.9	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	11	°C/W
Operating Temperature Range	T _J	-55 to 175	°C
Storage Temperature Range	T _{STG}	-55 to 175	°C

Notes:

- (1) Non-repetitive current pulse, 10/1000us Waveform.
- (2) Non-repetitive current pulse, 10/10000us Waveform.
- (3) Infinite HeatSink at T_A =50°C.
- (4) Measured on 8.3ms single half sine wave or equivalent square wave, duty cycle=4 perminute maximum.





Transient Voltage Suppressor

Electrical Characteristics (T_A=+25°C, unless otherwise noted)

Part Number	Reverse Stand-Off Votage V _R	Vol	down tage c@l _T	Test Current I _T	Maximum Clamping Voltage V _C @ I _{IPP}	Maximum Peak Pulse Current I _{IPP}	Maximun Reverse Leakage I _R @V _R
(Uni)	(V)	Min.(V)	Max.(V)	(mA)	(V)	(A)	(uA)
SM8S10CA	10	11.1	12.3	5	17	388	15
SM8S11CA	11	12.1	13.5	5	18.2	362	10
SM8S12CA	12	13.3	14.7	5	19.9	332	10
SM8S13CA	13	14.4	15.9	5	21.5	307	10
SM8S14CA	14	15.6	17.2	5	23.2	284	10
SM8S15CA	15	16.7	18.5	5	24.4	270	10
SM8S16CA	16	17.8	19.7	5	26	254	10
SM8S17CA	17	18.9	20.9	5	27.6	239	10
SM8S18CA	18	20	22.1	5	29.2	226	10
SM8S20CA	20	22.2	24.5	5	32.4	204	10
SM8S22CA	22	24.4	26.9	5	35.5	186	10
SM8S24CA	24	26.7	29.5	5	38.9	170	10
SM8S26CA	26	28.9	31.9	5	42.1	157	10
SM8S28CA	28	31.1	34.4	5	45.4	145	10
SM8S30CA	30	33.3	36.8	5	48.4	136	10
SM8S33CA	33	36.7	40.6	5	53.3	124	10
SM8S36CA	36	40	44.2	5	58.1	114	10
SM8S40CA	40	44.4	49.1	5	64.5	102	10
SM8S43CA	43	47.8	52.8	5	69.4	95.1	10



Transient Voltage Suppressor

(T_A=+25°C, unless otherwise noted) **Ratings and Characteristic Curves**

Figure 1: Peak Pulse Power Rating

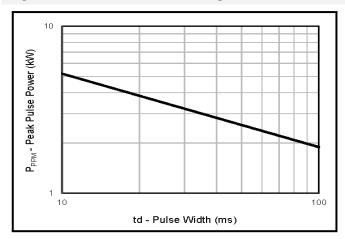


Figure 3: Pulse Waveform

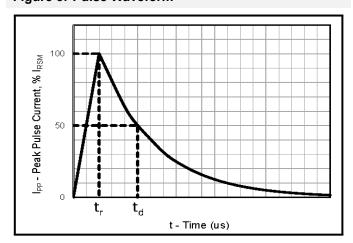


Figure 5: Steady State Power Dissipation Derating Curve

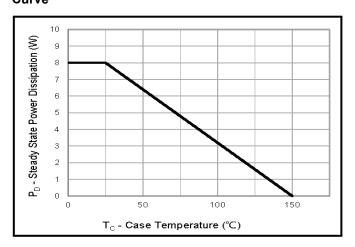


Figure 2: Pulse Derating Curve

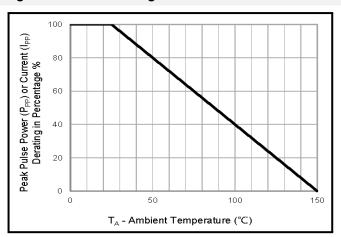


Figure 4: Typical Junction Capacitance

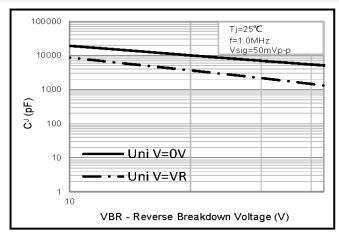
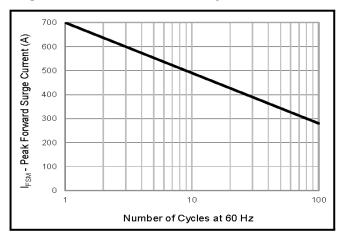


Figure 6: Maximum Non-Repetitive Peak Forward **Surge Current Uni-Directional Only**

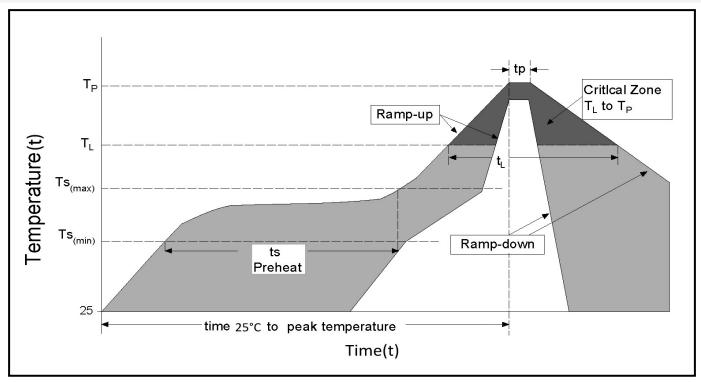


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Transient Voltage Suppressor

Soldering Parameters



Reflow (Lead-free assembly		
	- Temperature Min (T _S (min))	150°C	
Pre Heat	- Temperature Max (T _S (max))	200°C	
	- Time (min to max) (t _S)	60 - 180 secs	
Average ramp up rate (Lie	Average ramp up rate (Liquidus Temp (T _L) to peak)		
$T_{S}(max)$ to T_{L} -	T _S (max) to T _L - Ramp-up Rate		
Reflow	- Temperature (T _L) (Liquidus)	217°C	
Reliow	- Time (t _L)	60 -150 secs	
Peak Temp	Peak Temperature (T _P)		
Time within 5°C of actual	Time within 5°C of actual peak Temperature (t _p)		
Ramp-do	6°C/second max		
Time 25°C to pea	Time 25°C to peak Temperature (t)		
Do not	260°C		

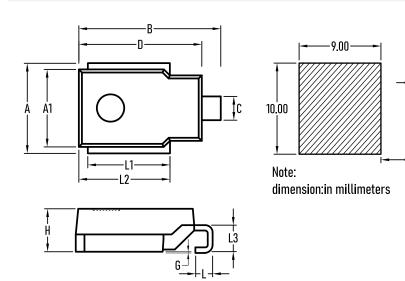




3.50

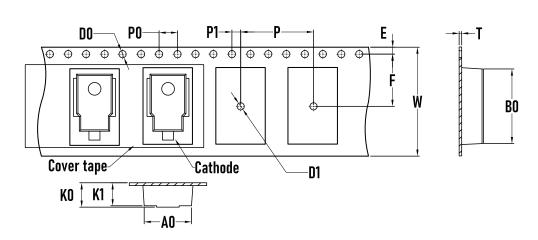
Transient Voltage Suppressor

Outline Drawing -DO-218



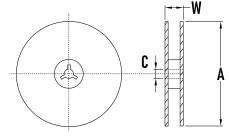
CVMDOL	MILLIMETER				
SYMBOL	MIN.	Тур.	MAX.		
Α	9.5	9.9	10.3		
A1	8.3	8.5	8.7		
В	15	15.6	16		
С	2.3	2.6	2.9		
D	13.3	13.5	13.7		
G	_	_	0.12		
Н	4.7	4.85	5		
L	1.5	2	2.5		
L1	8.7	9	9.3		
L2	9.7	10	10.3		
L3 2.5		3.0	3.5		

Packaging Tape - DO-218



SYMBOL	MILLIMETER
A0	11.00±0.1
В0	16.70±0.1
D0	1.55±0.1
D1	1.50±0.1
Е	1.75±0.1
F	13.250±0.1
K0	5.90±0.1
K1	5.60±0.1
Р	16.00±0.1
P0	4.00±0.1
P1	2.00±0.1
W	24.00±0.1
Т	0.40±0.01

Packaging Reel



SYMBOL	MILLIMETER
Α	330±2.0
С	13.5±0.5
W	29.0±2
Quantity	700PCS

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